

WN3S20S100C Dual power Schottky diode

Rev.01 - 14 November 2022

Product data sheet

1. General description

Dual common cathode power Schottky diode designed for high frequency switched mode power supplies in a TO220 plastic package.



2. Features and benefits

- Trench structure
- High junction temperature up to 150 °C
- Low forward voltage drop, negligible switching losses
- High efficiency

3. Applications

- DC to DC converters
- Freewheeling diode
- OR-ing diode
- · Switched mode power supply rectifier

4. Quick reference data

Table 1. Q	uick reference data						
Symbol	Parameter	Conditions	Notes	Values			Unit
Absolute	maximum rating						
V_{RRM}	repetitive peak reverse voltage			100			V
$I_{F(AV)}$	average forward current	δ = 0.5 ; square-wave pulse; T _{mb} ≤ 117 °C; per diode; <u>Fig. 1</u> ; <u>Fig. 2</u> ; <u>Fig. 3</u>		10			A
$I_{O(AV)}$	average output current	δ = 0.5 ; square-wave pulse; T _{mb} ≤ 113 °C; both diodes conducting		20			A
Symbol	Parameter	Conditions	Notes	Min Typ Max		Max	Unit
Static ch	aracteristics						
V _F	forward voltage	$I_F = 10 \text{ A}; T_j = 25 \text{ °C}; \text{ per diode}; Fig. 6$		- 0.90 1.00		V	
I _R	reverse current	V _R = 100 V; T _j = 25 °C; per diode; <u>Fig. 7; Fig. 8</u>		- 2.5 15		μA	

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5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	A1	anode 1	mb	
2	К	cathode		
3	A2	anode 2		K sym125
mb	К	mounting base; connected to cathode		

6. Ordering information

Table 3. Ordering information									
	Type number	Package	Orderable part number	Packing	Small packing	Package	Package		
		name		method	quantity	version	issue date		
	WN3S20S100C	TO220	WN3S20S100CQ	Tube	50	SOT78	13-Jun-2008		

7. Marking

Table 4. Marking codes	
Type number	Marking codes
WN3S20S100C	WN3S20S 100C

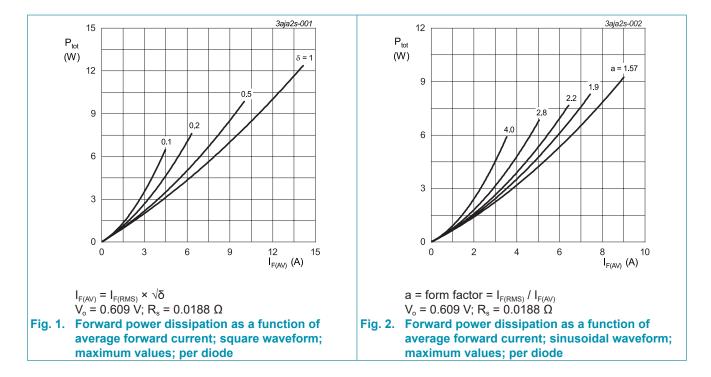
8. Limiting values

Table 5. Limiting values

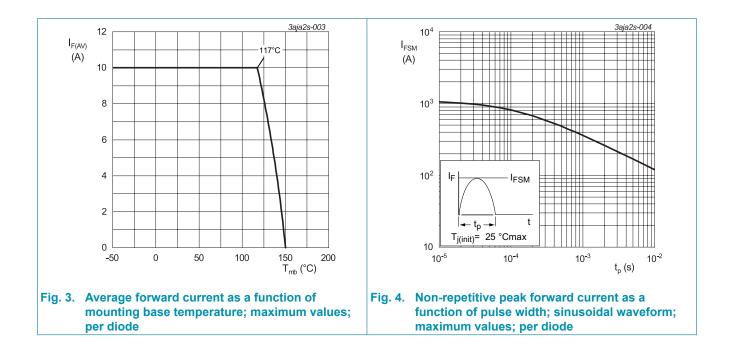
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Notes	Values	Unit
V_{RRM}	repetitive peak reverse voltage			100	V
V_{RWM}	crest working reverse voltage			100	V
V _R	reverse voltage	DC		100	V
I _{F(AV)}	average forward current	δ = 0.5 ; square-wave pulse; T _{mb} ≤ 117 °C; per diode; <u>Fig. 1</u> ; <u>Fig. 2</u> ; <u>Fig. 3</u>		10	A
I _{O(AV)}	average output current	δ = 0.5 ; square-wave pulse; T _{mb} ≤ 113 °C; both diodes conducting		20	A
I _{FSM}	non-repetitive peak forward current	t _p = 10 ms; T _{j(init)} = 25 °C; sine-wave pulse; per diode; <u>Fig. 4</u>		120	A
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; per diode		132	A
T _{stg}	storage temperature			-40 to 150	°C
T _j	junction temperature		[1]	-40 to 150	°C

[1] The heat generated must be less than the thermal conductivity from Junction to Ambient: $dP_{tot}/dT_j < 1/R_{th(j-a)}$

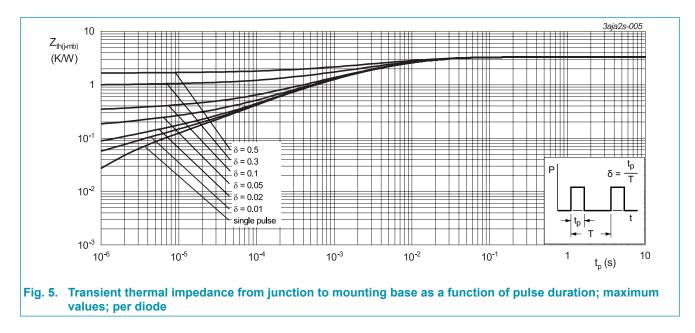


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9. Thermal characteristics

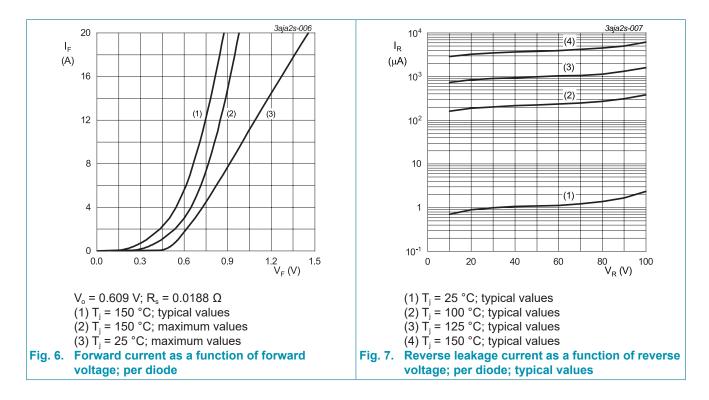
Table 6. Thermal characteristics								
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit	
$R_{\text{th(j-mb)}}$	thermal resistance from junction to mounting base	per diode; <u>Fig. 5</u>		-	-	3.3	K/W	
		both diodes conducting		-	-	1.9	K/W	
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	in free air		-	60	-	K/W	



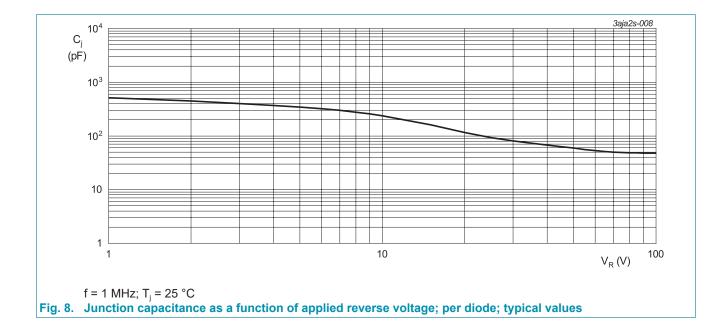
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10. Characteristics

Table 7. Characteristics								
Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
Static characteristics								
$V_{\rm F}$	forward voltage	I _F = 10 A; T _j = 25 °C; per diode; <u>Fig. 6</u>		-	0.90	1.00	V	
		I _F = 10 A; T _j = 125 °C; per diode; <u>Fig. 6</u>		-	0.76	-	V	
I _R reverse current		V _R = 100 V; T _j = 25 °C; per diode; <u>Fig. 7; Fig. 8</u>		-	2.5	15	μA	
		V _R = 100 V; T _j = 125 °C; per diode; <u>Fig. 7</u> ; <u>Fig. 8</u>		-	1.7	10	mA	

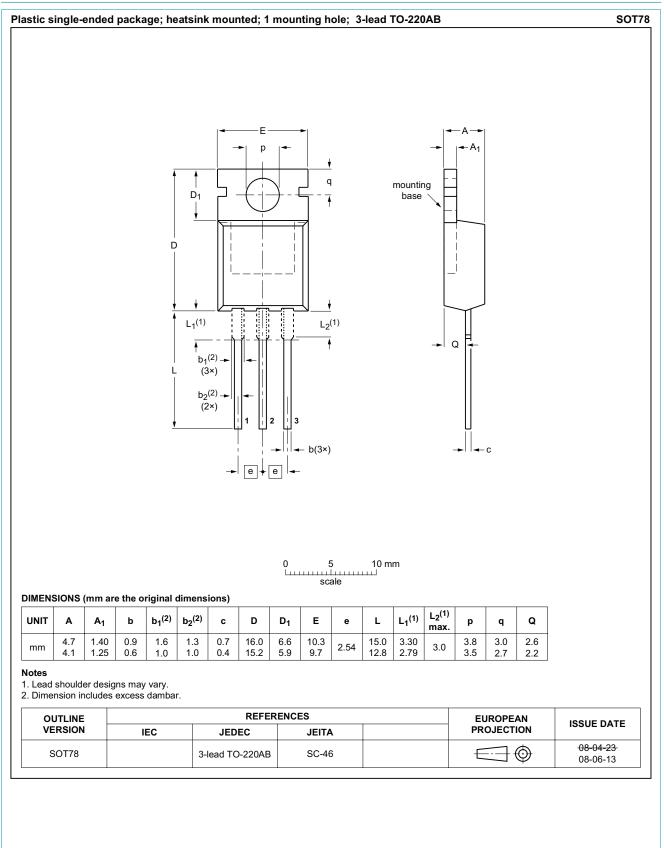


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11. Package outline



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12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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